

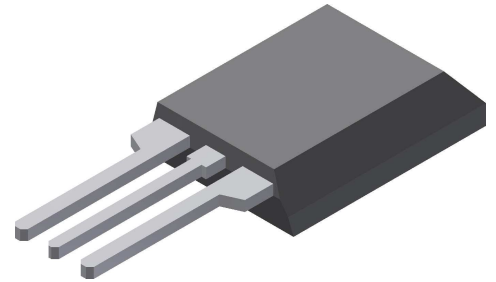
# HiPerFRED<sup>2</sup>

|           |      |       |
|-----------|------|-------|
| $V_{RRM}$ | = 2x | 300 V |
| $I_{FAV}$ | =    | 30 A  |
| $t_{rr}$  | =    | 35 ns |

High Performance Fast Recovery Diode  
 Low Loss and Soft Recovery  
 Phase leg

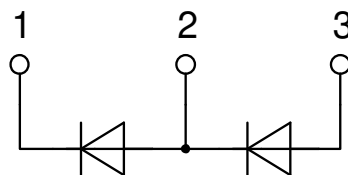
Part number

**DPG30P300PJ**



Backside: isolated

 E72873



## Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

## Package: ISOPLUS220

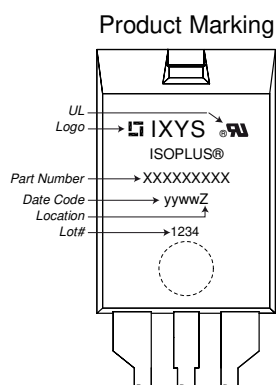
- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

## Disclaimer Notice

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| Fast Diode |                                              |                                                                                    |                                | Ratings                        |      |      |               |
|------------|----------------------------------------------|------------------------------------------------------------------------------------|--------------------------------|--------------------------------|------|------|---------------|
| Symbol     | Definition                                   | Conditions                                                                         |                                | min.                           | typ. | max. | Unit          |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                                                      |                                |                                |      | 300  | V             |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                                                      |                                |                                |      | 300  | V             |
| $I_R$      | reverse current, drain current               | $V_R = 300\text{ V}$                                                               | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1    | $\mu\text{A}$ |
|            |                                              | $V_R = 300\text{ V}$                                                               | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 0.2  | mA            |
| $V_F$      | forward voltage drop                         | $I_F = 30\text{ A}$                                                                | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1.27 | V             |
|            |                                              | $I_F = 60\text{ A}$                                                                |                                |                                |      | 1.57 | V             |
|            |                                              | $I_F = 30\text{ A}$                                                                | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 0.98 | V             |
|            |                                              | $I_F = 60\text{ A}$                                                                |                                |                                |      | 1.30 | V             |
| $I_{FAV}$  | average forward current                      | $T_C = 135^{\circ}\text{C}$<br>rectangular $d = 0.5$                               | $T_{VJ} = 175^{\circ}\text{C}$ |                                |      | 30   | A             |
| $V_{F0}$   | threshold voltage                            | } for power loss calculation only                                                  |                                | $T_{VJ} = 175^{\circ}\text{C}$ |      | 0.60 | V             |
| $r_F$      | slope resistance                             |                                                                                    |                                |                                |      | 10.3 | m $\Omega$    |
| $R_{thJC}$ | thermal resistance junction to case          |                                                                                    |                                |                                |      | 1.05 | K/W           |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                                                    |                                |                                | 0.5  |      | K/W           |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                                                         |                                |                                |      | 145  | W             |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$                 | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 450  | A             |
| $C_J$      | junction capacitance                         | $V_R = 200\text{ V}$ $f = 1\text{ MHz}$                                            | $T_{VJ} = 25^{\circ}\text{C}$  |                                | 60   |      | pF            |
| $I_{RM}$   | max. reverse recovery current                | } $I_F = 30\text{ A}; V_R = 200\text{ V}$<br>$-di_F/dt = 200\text{ A}/\mu\text{s}$ |                                | $T_{VJ} = 25^{\circ}\text{C}$  |      | 3    | A             |
|            |                                              |                                                                                    |                                | $T_{VJ} = 125^{\circ}\text{C}$ |      | 8.5  | A             |
| $t_{rr}$   | reverse recovery time                        |                                                                                    |                                | $T_{VJ} = 25^{\circ}\text{C}$  |      | 35   | ns            |
|            |                                              |                                                                                    |                                | $T_{VJ} = 125^{\circ}\text{C}$ |      | 65   | ns            |

| Package ISOPLUS220   |                                                              |                      |                                         | Ratings |      |      |      |
|----------------------|--------------------------------------------------------------|----------------------|-----------------------------------------|---------|------|------|------|
| Symbol               | Definition                                                   | Conditions           |                                         | min.    | typ. | max. | Unit |
| I <sub>RMS</sub>     | RMS current                                                  | per terminal         |                                         |         |      | 35   | A    |
| T <sub>VJ</sub>      | virtual junction temperature                                 |                      |                                         | -55     |      | 175  | °C   |
| T <sub>op</sub>      | operation temperature                                        |                      |                                         | -55     |      | 150  | °C   |
| T <sub>stg</sub>     | storage temperature                                          |                      |                                         | -55     |      | 150  | °C   |
| Weight               |                                                              |                      |                                         |         | 2    |      | g    |
| F <sub>C</sub>       | mounting force with clip                                     |                      |                                         | 20      |      | 60   | N    |
| d <sub>Spp/App</sub> | creepage distance on surface   striking distance through air | terminal to terminal |                                         | 1.0     |      |      | mm   |
| d <sub>Spb/Apb</sub> |                                                              | terminal to backside |                                         | 3.0     |      |      | mm   |
| V <sub>ISOL</sub>    | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; I <sub>ISOL</sub> ≤ 1 mA | 3600    |      |      | V    |
|                      |                                                              | t = 1 minute         |                                         | 3000    |      |      | V    |



### Part description

D = Diode  
 P = HiPerFRED  
 G = extreme fast  
 30 = Current Rating [A]  
 P = Phase leg  
 300 = Reverse Voltage [V]  
 PJ = ISOPLUS220AB (3)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DPG30P300PJ     | DPG30P300PJ        | Tube          | 50       | 508134   |

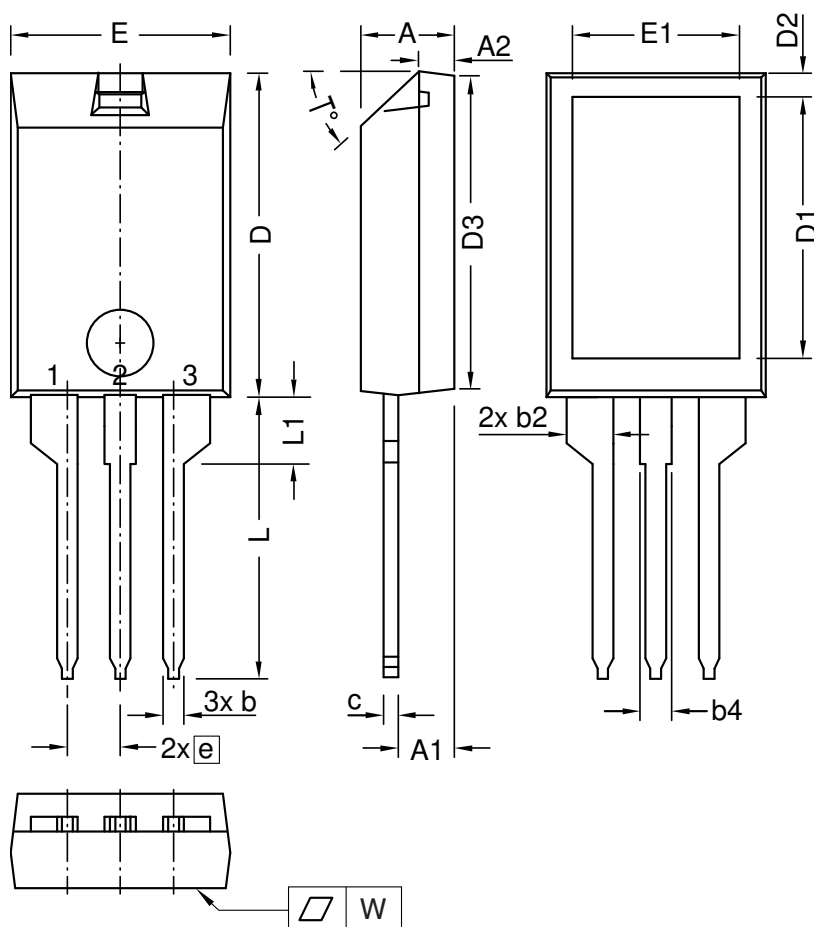
| Similar Part | Package        | Voltage class |
|--------------|----------------|---------------|
| DPG30P400PJ  | ISOPLUS220 (3) | 400           |

### Equivalent Circuits for Simulation

\* on die level

$T_{VJ} = 175^{\circ}\text{C}$

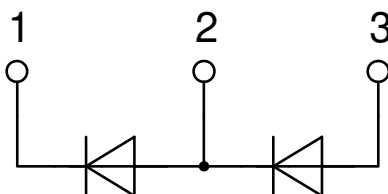
|                                                                                     |                    |                   |    |
|-------------------------------------------------------------------------------------|--------------------|-------------------|----|
|  |                    | <b>Fast Diode</b> |    |
| $V_{0\max}$                                                                         | threshold voltage  | 0.6               | V  |
| $R_{0\max}$                                                                         | slope resistance * | 7.1               | mΩ |

**Outlines ISOPLUS220**


| Dim. | Millimeters |       | Inches    |       |
|------|-------------|-------|-----------|-------|
|      | min         | max   | min       | max   |
| A    | 4.00        | 5.00  | 0.157     | 0.197 |
| A1   | 2.50        | 3.00  | 0.098     | 0.118 |
| A2   | 1.60        | 1.80  | 0.063     | 0.071 |
| b    | 0.90        | 1.30  | 0.035     | 0.051 |
| b2   | 2.35        | 2.55  | 0.093     | 0.100 |
| b4   | 1.25        | 1.65  | 0.049     | 0.065 |
| c    | 0.70        | 1.00  | 0.028     | 0.039 |
| D    | 15.00       | 16.00 | 0.591     | 0.630 |
| D1   | 12.00       | 13.00 | 0.472     | 0.512 |
| D2   | 1.10        | 1.50  | 0.043     | 0.059 |
| D3   | 14.90       | 15.50 | 0.587     | 0.610 |
| E    | 10.00       | 11.00 | 0.394     | 0.433 |
| E1   | 7.50        | 8.50  | 0.295     | 0.335 |
| e    | 2.54 BSC    |       | 0.100 BSC |       |
| L    | 13.00       | 14.50 | 0.512     | 0.571 |
| L1   | 3.00        | 3.50  | 0.118     | 0.138 |
| T°   | 42.5        | 47.5  |           |       |
| W    | -           | 0.1   | -         | 0.004 |

Die konvexe Form des Substrates ist typ. < 0.04 mm über der Kunststoffoberfläche der Bauteilunterseite  
 The convex bow of substrate is typ. < 0.04 mm over plastic surface level of device bottom side

Die Gehäuseabmessungen entsprechen dem Typ TO-273 gemäß JEDEC außer D und D1.  
 This drawing will meet all dimensions requirement of JEDEC outline TO-273 except D and D1.



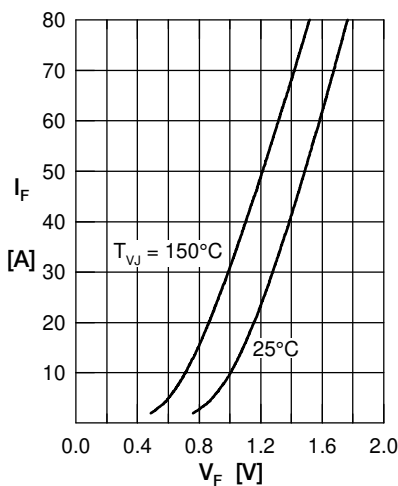
**Fast Diode**


Fig. 1 Forward current  $I_F$  versus  $V_F$

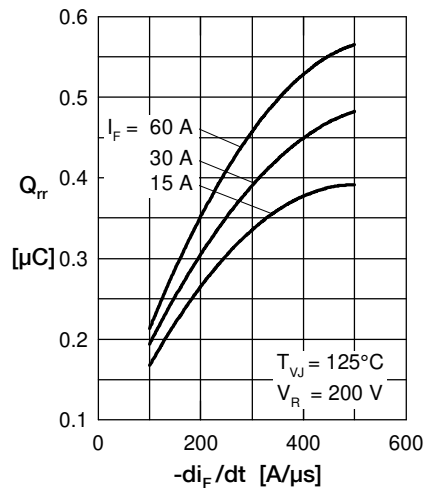


Fig. 2 Typ. reverse recov. charge  $Q_{rr}$  versus  $-di_F/dt$

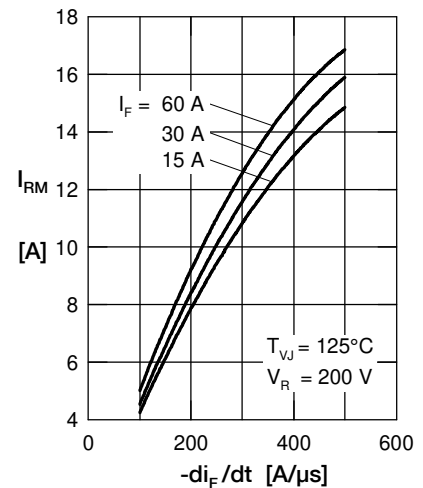


Fig. 3 Typ. reverse recov. current  $I_{RM}$  versus  $-di_F/dt$

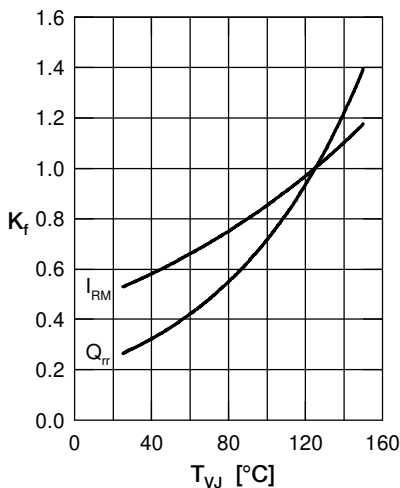


Fig. 4 Typ. dynamic parameters  $Q_{rr}$ ,  $I_{RM}$  versus  $T_{VJ}$

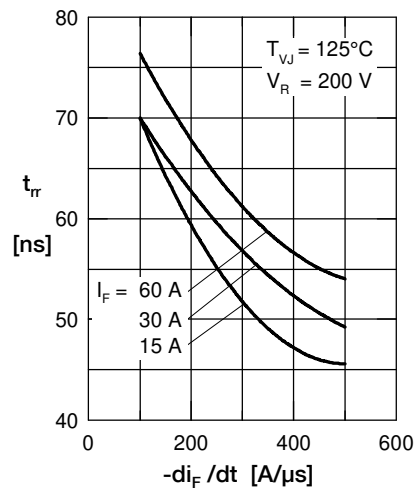


Fig. 5 Typ. reverse recov. time  $t_{rr}$  versus  $-di_F/dt$

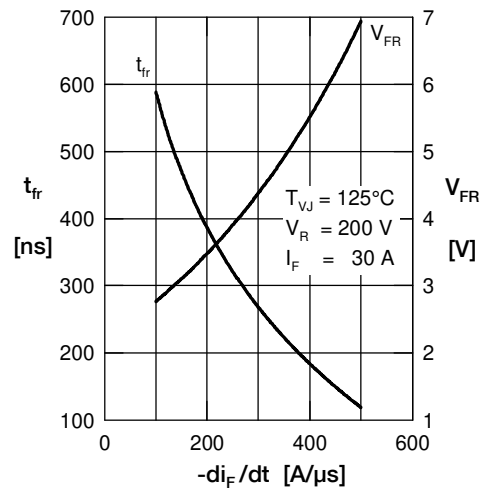


Fig. 6 Typ. forward recovery voltage  $V_{FR}$  & time  $t_{fr}$  versus  $di_F/dt$

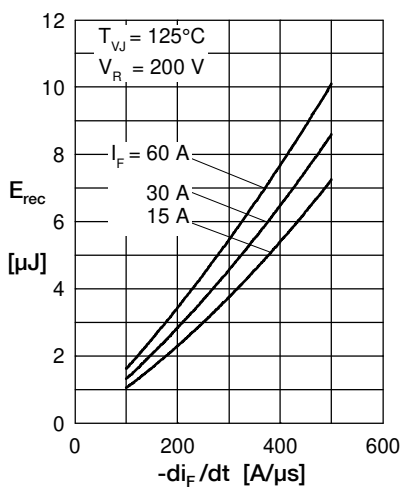


Fig. 7 Typ. recovery energy  $E_{rec}$  versus  $-di_F/dt$

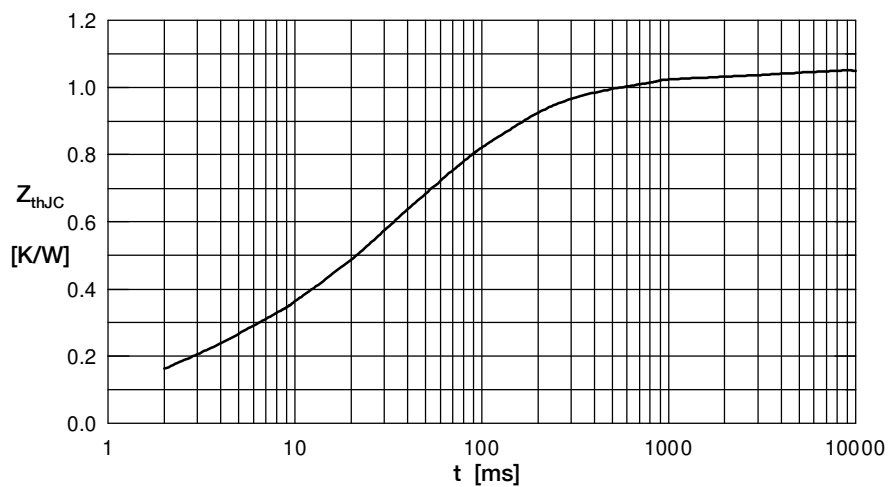


Fig. 8 Transient thermal impedance junction to case